





#### P-CHANNEL ENHANCEMENT MODE MOSFET

### **Features**

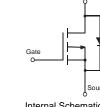
- Low R<sub>DS(ON)</sub>:
  - $40 \text{ m}\Omega$  @V<sub>GS</sub> = -4.5V
  - $70 \text{ m}\Omega$  @V<sub>GS</sub> = -2.5V
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- "Green" Device (Note 4)

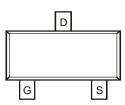
### **Mechanical Data**

- Case: SC-59
- Case Material Molded Plastic. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 4
- Ordering Information: See page 4
  - Weight: 0.014 grams (approximate)

SC-59







**TOP VIEW** 

Internal Schematic

Pin Configuration

## **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		$V_{DSS}$	-20	V
Gate-Source Voltage		V <sub>GSS</sub>	±12	V
Drain Current (Note 1) Continuous	$T_A = 25$ °C $T_A = 70$ °C	I <sub>D</sub>	-4.6 -3.7	А
Pulsed Drain Current (Note 2)		I <sub>DM</sub>	-18	Α
Body-Diode Continuous Current (Note 1)		Is	2.0	Α

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	$P_{D}$	1.25	W
Thermal Resistance, Junction to Ambient (Note 1); Steady-State	$R_{ hetaJA}$	100	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

- 1. Device mounted on 1"x1", FR-4 PC board with 2 oz. Copper and test pulse width  $t \le 10s$ .
- 2. Repetitive Rating, pulse width limited by junction temperature.
- 3. No purposefully added lead.
- 4. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

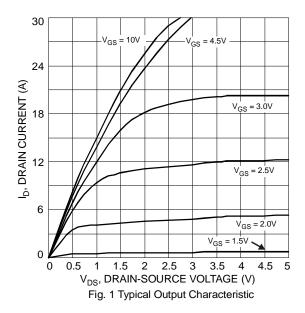


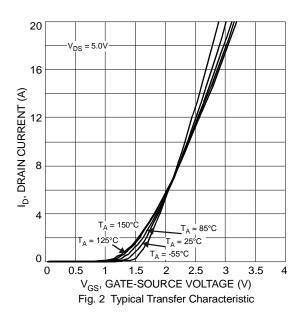
# **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
STATIC PARAMETERS							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	_	_	V	$I_D = -250 \mu A, V_{GS} = 0 V$	
Zero Gate Voltage Drain Current T <sub>J</sub> = 25°C	I <sub>DSS</sub>	_	_	-1	μΑ	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Body Leakage Current	I <sub>GSS</sub>	_	_	±100	nA	$V_{DS} = 0V, V_{GS} = \pm 12V$	
Gate Threshold Voltage	V <sub>GS(th)</sub>	-0.6	-0.96	-1.2	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
On State Drain Current (Note 5)	I <sub>D (ON)</sub>	-15		_	Α	$V_{GS} = -4.5V, V_{DS} = -5V$	
Static Drain-Source On-Resistance (Note 5)	R <sub>DS (ON)</sub>	_	29 55	40 70	mΩ	V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -4.6A V <sub>GS</sub> = -2.5V, I <sub>D</sub> = -3.8A	
Forward Transconductance (Note 5)	<b>g</b> FS	_	9	_	S	$V_{DS} = -10V, I_D = -4.5A$	
Diode Forward Voltage (Note 5)	$V_{SD}$	-0.5	-0.72	-1.4	V	$I_S = -2.1A$ , $V_{GS} = 0V$	
Maximum Body-Diode Continuous Current (Note 1)	Is	_		1.7	Α	_	
DYNAMIC PARAMETERS (Note 6)							
Input Capacitance	Ciss	_	820	_	pF	15)()(	
Output Capacitance	Coss	_	200	_	pF	$V_{DS} = -15V, V_{GS} = 0V$ - f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	160	_	pF	T = T.OWINZ	
Gate Resistance		_	2.5	_	Ω	$V_{DS} = 0V, V_{GS} = 0V$ f = 1.0MHz	
SWITCHING CHARACTERISTICS							
Total Gate Charge	$Q_{G}$	_	10.1	_		$V_{DS} = -10V, V_{GS} = -4.5V,$ $I_{D} = -4.5A$	
Gate-Source Charge	$Q_{GS}$	_	1.5	_	nC		
Gate-Drain Charge	$Q_{GD}$	_	4.3	_		ID = -4.5A	
Turn-On Delay Time	t <sub>d(on)</sub>	_	4.4	_		$V_{DS} = -10V$ , $V_{GS} = -4.5V$ , $I_{D} = -1A$ , $R_{G} = 6.0\Omega$	
Rise Time	t <sub>r</sub>		9.9	_	ns		
Turn-Off Delay Time	t <sub>d(off)</sub>	_	28.0	_	115		
Fall Time	t <sub>f</sub>		23.4				

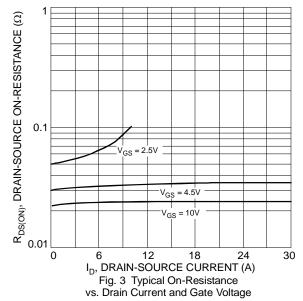
Notes:

- 5. Test pulse width  $t = 300 \mu s$ .
- 6. Guaranteed by design. Not subject to production testing.









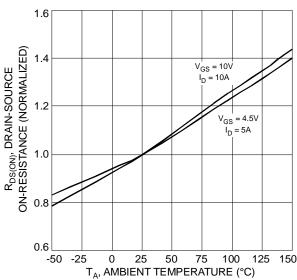
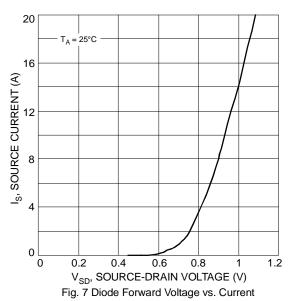
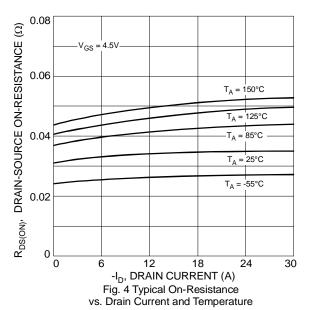


Fig. 5 Normalized On-Resistance vs. Ambient Temperature





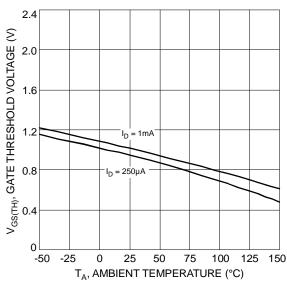
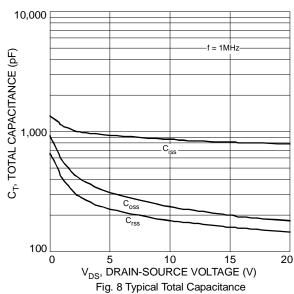


Fig. 6 Gate Threshold Variation vs. Ambient Temperature



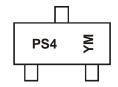


# Ordering Information (Note 7)

Part Number	Case	Packaging
DMP2066LSN-7	SC-59	3000/Tape & Reel

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



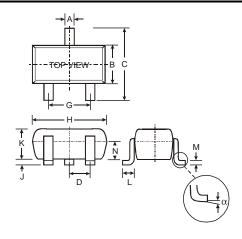
PS4 = Product Type Marking Code YM = Date Code Marking Y = Year ex: V = 2008

M = Month ex: 9 = September

#### Date Code Key

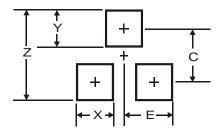
Year	2008		2009	2010		2011	2012		2013	2014		2015
Code	V		W	X		Υ	Z		Α	В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

# **Package Outline Dimensions**



SC-59					
Dim	Min	Max			
Α	0.35	0.50			
В	1.50	1.70			
С	2.70	3.00			
D	0.95				
G	1.90				
Н	2.90	3.10			
J	0.013	0.10			
K	1.00	1.30			
L	0.35	0.55			
M	0.10	0.20			
N	0.70	0.80			
α	0°	8°			
All Dimensions in mm					

## **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	3.4
Х	0.8
Υ	1.0
С	2.4
E	1.35



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